

Evaporation-Induced Self-Assembly of Hybrid Bridged Silsesquioxane Film and Particulate Mesophases with Integral Organic Functionality

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Abstract: We report an evaporation-induced self-assembly procedure to prepare poly(bridged silsesquioxane) thin-film and particulate mesophases that incorporate organic moieties (**1–3**) into periodic, mesostructured frameworks as molecularly dispersed bridging ligands. Capacitance–voltage measurements along with a variety of structural characterization procedures were performed to begin to elucidate structure–property relationships of this new class of surfactant-templated mesophases. We observed a consistent trend of increasing modulus and hardness and decreasing dielectric constant with substitution of the bridged silsesquioxane ($\equiv\text{Si}-(\text{CH}_2)_2-\text{Si}\equiv$) for siloxane ($\equiv\text{Si}-\text{O}-\text{Si}\equiv$) in the framework. This preliminary evidence suggests that the introduction of integral organic groups into the frameworks of mesoporous materials can result in synergistic properties, promising an unprecedented ability to tune properties and function.

Since the discovery of surfactant-templated silica mesophases,¹ the development of organic modification schemes to impart functionality to the pore surfaces has received much attention.^{2–13} Most recently, using the general class of compounds referred to as bridged silsesquioxanes $(\text{RO})_3\text{Si}-\text{R}'-\text{Si}(\text{OR})_3$ ^{14,15} (Scheme 1), three research groups have reported the formation of a new class of poly(bridged silsesquioxane) mesophases (BSQMs) with integral organic functionality.^{16–19}

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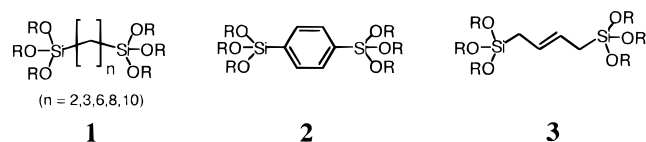
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Scheme 1. Chemical Formulas of Bridged Silsesquioxane Monomers **1–3**



In contrast to previous hybrid mesophases in which organic ligands or molecules are situated on pore surfaces, this class of materials necessarily incorporates the organic constituents into the framework as molecularly dispersed bridging ligands. Although it is anticipated that this new mesostructural organization should result in synergistic properties derived from the molecular-scale mixing of the inorganic and organic components, few properties of BSQMs have been measured. In addition, samples prepared to date have been in the form of granular precipitates, precluding their use in applications such as membranes, fluidics, and low-*k* dielectric films needed for all foreseeable future generations of microelectronics. Here we use an evaporation-induced self-assembly procedure²⁰ to prepare BSQM films and spherical nanoparticles. Capacitance–voltage measurements along with a variety of structural characterization procedures were performed to begin to elucidate structure–property relationships of this new class of thin-film and particulate mesophases.

The initially reported syntheses of BSQMs involved precipitation in basic aqueous media followed by aging for periods up to several days. To form homogeneous films, precipitation must be avoided, and the self-assembly process must be accomplished within the brief time span of the dip- or spin-coating operation (at most several seconds). To meet these requirements, we

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prepare dilute, homogeneous, ethanolic solutions that suppress silica/surfactant self-assembly and employ acidic conditions that retard siloxane condensation. In a typical synthesis procedure, requisite amounts of **1** (from Gelest and triply distilled prior to use), **2** (synthesized according to ref 15), or **3** (synthesized according to ref 15)²¹ are dissolved in ethanol followed by addition of 1–8 wt % surfactant [cationic (CTAB, CH₃-(CH₂)₁₅N⁺(CH₃)₃Br⁻), nonionic (Brij-56, C₁₆H₃₃(OCH₂CH₂)₁₀-OH), anionic (SDS, C₁₂H₂₅OSO₃⁻Na⁺), or block copolymer (P123, H(OCH₂CH₂)₂₀(OCH(CH₃)CH₂)₇₀(OCH₂CH₂)₂₀OH)] and an aqueous solution of HCl (0.1–1.0 N). The investigated range of starting compositions is represented by the molar ratios Si:EtOH:H₂O:HCl:surfactant = 1:22:5:0.004:(0.054–0.18). To evaluate the effect of substitution of bridged silsesquioxanes for siloxanes on the properties of resultant thin-film mesostructures, a series of films was prepared with varying ratios of TEOS and (EtO)₃Si-(CH₂)₂-Si(OEt)₃. For this series, the starting compositions are represented by the molar ratios TEOS:**1** (*n* = 2):EtOH:H₂O:HCl:surfactant = (0.3–3):1:0.25:0.044:0.8:0.00084. In all cases the initial surfactant concentration (*c*₀) is much less than the critical micelle concentration (cmc), implying mesoscale homogeneity of the starting sols.

Films were prepared by spin- or dip-coating,²² and nanoparticles were prepared by an aerosol-assisted self-assembly process described previously.²³ In both cases, preferential ethanol evaporation concentrates the sol in water, nonvolatile surfactant, and organically bridged polysilsesquioxane species. By choosing the initial acid concentration to retard the competing process of siloxane condensation, we exploit the progressively increasing surfactant concentration to drive self-assembly of polysilsesquioxane-surfactant micelles and their further organization into liquid crystalline mesophases. Pre-existing, incipient polysilsesquioxane-surfactant mesostructures (which exist at solid-liquid and liquid-vapor interfaces at *c* < cmc) serve to nucleate and orient the mesophase development.^{22,23} The result is rapid (several seconds) formation of thin-film or particulate BSQMs that are oriented with respect to the solid-liquid and/or liquid-vapor interfaces. Through variation of the shape of the surfactant along with its charge and initial concentration, this evaporation-induced self-assembly route can be used to attain a range of thin-film or particulate mesophases.

Figure 1 shows X-ray diffraction (XRD) results for thin-film bridged polysilsesquioxane mesophases prepared from the ethylene-bridged silsesquioxane precursor (**1** with *n* = 2) with CTAB, Brij-56, or SDS surfactant before and after calcination at 250 °C in N₂. The multiple sharp peaks observed for the uncalcined SDS system and the virtual elimination of these peaks after calcination are consistent with an [001]-oriented lamellar thin-film mesophase, as is commonly observed for silica thin-film mesophases prepared from SDS and TEOS.²⁴ The CTAB and Brij-56 systems are characterized by single intense peaks that shift slightly to higher 2θ values (lower *d*-spacing) upon calcination. This behavior is similar to that observed previously for hexagonal and cubic thin-film mesophases prepared from TEOS or TEOS plus various organotrialkoxysilane co-monomers.^{22,25} In combination with TEM results (discussed below), we interpret the major peak in the CTAB

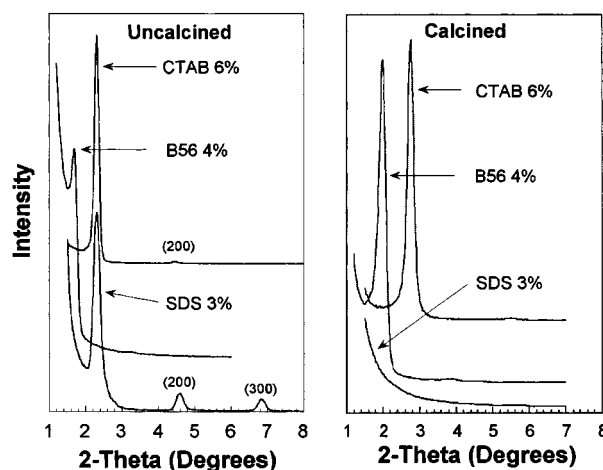


Figure 1. XRD of the uncalcined and calcined thin-film mesophases prepared using ethylene-bridged silsesquioxane precursor (**1**, with *n* = 2) and CTAB (6%), Brij-56 (4%), or SDS (3%) surfactants.

system as the (100) reflection of a one-dimensional hexagonal mesophase with *d* = 3.4 nm. The major XRD peak in the Brij-56 system may be interpreted as a (200) reflection of a cubic mesophase with *a* = 9.2 nm.

TEM micrographs of calcined thin-film specimens evaluated by XRD are shown in Figure 2. The striped and hexagonal close-packed textures observed for the 6 wt % CTAB-derived film (Figure 2A) are characteristic of a one-dimensional hexagonal mesophase with *d*-spacing ≈ 3.3–3.5 nm, consistent with XRD results. Interestingly, we observe undulations and defects in the stripe pattern in a plane normal to the substrate surface, whereas for hexagonal thin-film mesophases prepared from TEOS these features are observed only in planes parallel to the substrate surface.²² Figure 2B shows a cross section of the film prepared with 4 wt % Brij-56. Based on the hexagonal pattern of spots and the 5.3-nm spot-to-spot spacing, we interpret the upper right region as a [111] orientation of a face-centered cubic structure with *a* ≈ 9.1–9.3 nm, consistent with XRD results and previous cubic thin-film mesophases prepared from Brij-56 and TEOS.²⁰ Figure 2C shows the TEM micrograph of a calcined spherical nanoparticle prepared using the phenylene-bridged precursor **2** with 8 wt % P123 block copolymer surfactant. Regions adjacent to the particle circumference, which correspond to the thinnest regions of the specimen in the imaging direction, exhibit a hexagonal close-packed texture. We interpret this structure as a hexagonal mesophase composed of close-packed cylindrical pore channels aligned parallel to the particle circumference. This orientation arises from the initial nucleation of the hexagonal mesophase at the air-liquid interface and its growth inward, driven by an evaporation-induced radial concentration gradient.²³ We note that particles prepared from the comparable TEOS/8 wt % P123 system exhibit a multilamellar vesicular mesostructure.²³ Figure 2D shows the TEM micrograph of calcined spherical nanoparticles prepared using precursor **3** with 8 wt % P123 block copolymer surfactant. This multilamellar vesicular structure is composed of concentric bridged polysilsesquioxane layers containing integral vinyl functionality.

The porosity of the thin-film specimens prepared from **1** with 6 wt % CTAB or 4 wt % Brij-56 was characterized by nitrogen sorption measurements performed on film specimens using a surface acoustic wave (SAW) technique.²⁶ The SAW N₂ sorption

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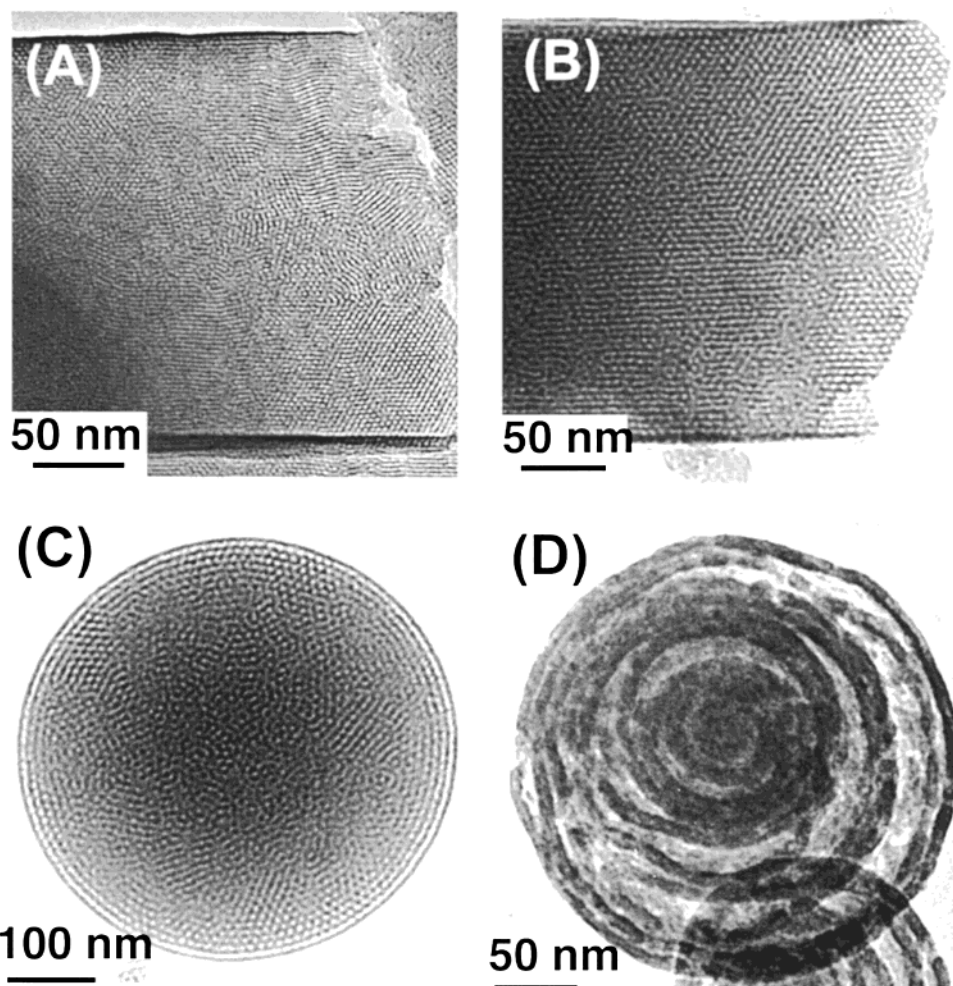


Figure 2. TEM micrograph of calcined bridged polysilsesquioxane thin-film and particle mesophases prepared using (A) precursor **1** and CTAB (6%); (B) precursor **1** and Brij-56 (4%); (C) precursor **2** and P123 (8%); and (D) precursor **3** and P123 (8%).

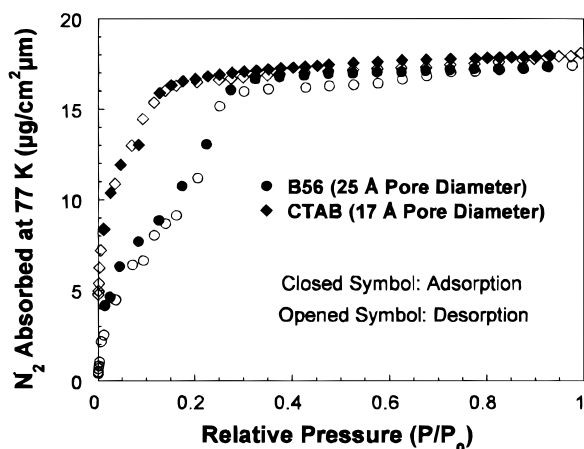


Figure 3. Surface acoustic wave (SAW)-based nitrogen sorption isotherms of the calcined thin-film mesophases prepared using ethylene-bridged silsesquioxane precursor **1** and CTAB (6%) or Brij-56 (4%) surfactants.

isotherms shown in Figure 3 are qualitatively consistent with those previously obtained for the corresponding TEOS-derived films²² and typical of surfactant-templated mesophases in general. Based on a cylindrical pore model, we used the ratio

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of the thickness-normalized pore volume and surface area to calculate hydraulic pore diameters of 1.8 and 2.5 nm, respectively, for the CTAB and Brij-56 films.

Retention of the bridging organic ligands in the calcined specimens was confirmed using ¹³C and ²⁹Si MAS NMR spectroscopy. For powders prepared from **1** with 6 wt % CTAB, we observed a large ¹³C resonance at 5.2 ppm, corresponding to the ethylene bridge, and a very broad ²⁹Si resonance at -58.5 ppm, corresponding to trifunctional (T) silicons.²⁷ There was no evidence of tetrafunctional Q silicons at -101 or -108 ppm, implying complete retention of the bridging ligands. For the phenylene-bridged system prepared from **2** with 8 wt % P123, we observed a ¹³C resonance at 133.4 ppm corresponding to the phenylene bridge and ²⁹Si resonances at -71.0 and -78.2 ppm, corresponding to T² and T³ species, respectively¹⁵ (where the superscript denotes the number of bridging oxygens covalently bonded to the trifunctional silicon center). Again, there was no evidence of Q silicons.

To begin to establish structure–porosity relationships, we prepared a series of films from TEOS and **1** ($n = 2$) with molar ratios TEOS:**1** = 75:25 (TB₁), 50:50 (TB₂), and 25:75 (TB₃). Synthesis and processing procedures were chosen to create isotropic disordered (wormlike) thin-film mesophases¹⁷ with comparable film thicknesses (measured by spectroscopic ellipsometry) and porosities (measured by analyses of SAW-based

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Table 1. Properties of Calcined TEOS//($\equiv\text{Si}-(\text{CH}_2)_2-\text{Si}\equiv$) Mesoporous Thin Films Prepared with 4 wt % Brij-56 Surfactant

framework (TEOS: silsesquioxane)	thickness (Å)	dielectric constant	porosity (%)	modulus (GPa)	hardness (GPa)
TB ₁ (75:25)	3135	2.15	56	3.5	0.35
TB ₂ (50:50)	3154	2.13	53	3.7	0.39
TB ₃ (25:75)	3015	1.98	56	4.3	0.48

N₂ sorption isotherms). After calcination at 350 °C under N₂ to remove the surfactant templates, all films were vapor-treated with hexamethyldisilazane to avoid water adsorption. Table 1 compares values of the dielectric constants (measured using a standard capacitance–voltage technique employing a mercury probe), Young's modulus, and hardness (modulus and hardness calculated from nanoindentation measurements at a constant indentation depth, assuming a Poisson ratio of 0.2). We observe a consistent trend of increasing modulus and hardness and decreasing dielectric constant with substitution of the bridged silsesquioxane ($\equiv\text{Si}-\text{CH}_2)_2-\text{Si}\equiv$) for siloxane ($\equiv\text{Si}-\text{O}-\text{Si}\equiv$)

in the framework. This preliminary evidence suggests that introduction of integral organic groups into the frameworks of mesoporous materials can result in synergistic properties, promising an unprecedented ability to tune properties and function. The trend of increasing mechanical performance and decreasing dielectric constant observed here is of immediate and crucial interest to the burgeoning field of low-*k* dielectrics.

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